

FMV30N60S1

FUJI POWER MOSFET

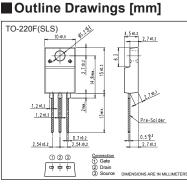
Super J-MOS series

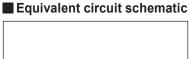
N-Channel enhancement mode power MOSFET

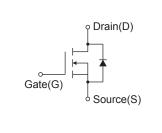
Features
Low on-state resistance
Low switching loss
easy to use (more controllabe switching dV/dt by R_g)

Applications

UPS Server Telecom Power conditioner system Power supply







Absolute Maximum Ratings at Tc=25°C (unless otherwise specified)

Description	Symbol	Characteristics	Unit	Remarks
Duraine Courses Maltana	V _{DS}	600	V	
Drain-Source Voltage	VDSX	600	V	V _{GS} =-30V
Continuous Dusin Current		±30	А	Tc=25°C Note*1
Continuous Drain Current	ID	±19	А	Tc=100°C Note*1
Pulsed Drain Current	IDP	±90	А	
Gate-Source Voltage	V _{GS}	±30	V	
Repetitive and Non-Repetitive Maximum Avalanche Current	lar	6.6	А	Note *2
Non-Repetitive Maximum Avalanche Energy	Eas	849.2	mJ	Note *3
Maximum Drain-Source dV/dt	dV _{DS} /dt	50	kV/µs	V _{DS} ≤ 600V
Peak Diode Recovery dV/dt	dV/dt	12	kV/µs	Note *4
Peak Diode Recovery -di/dt	-di/dt	100	A/µs	Note *5
Mentineum Deuten Dissination		2.16	10/	T₂=25°C
Maximum Power Dissipation	PD	90	W	Tc=25°C
One wetting and Otagona Tampanatura was as	Tch	150	°C	
Operating and Storage Temperature range	Tstg	-55 to +150	°C	
Isolation Voltage	Viso	2	kVrms	t=60sec,f=60Hz

Note *1 : Limited by maximum channel temperature.

Note *2 : T_{ch}≤150°C, See Fig.1 and Fig.2 Note *3 : Starting T_{ch}=25°C, I_{AS}=4A, L=97.3mH, V_{DD}=60V, R_G=50Ω, See Fig.1 and Fig.2

EAs limited by maximum channel temperature and avalanche current.

Note *4 : $I_{F} \le I_{D}$, $-di/dt = 100 A/\mu s$, $V_{DD} \le 400V$, $T_{ch} \le 150^{\circ}C$. Note *5 : $I_{F} \le -I_{D}$, $dV/dt = 12kV/\mu s$, $V_{DD} \le 400V$, $T_{ch} \le 150^{\circ}C$.

Electrical Characteristics at Tc=25°C (unless otherwise specified) Static Ratings

Description	Symbol	Conditions		min.	typ.	max.	Unit
Drain-Source Breakdown Voltage	BV _{DSS}	l₀=250μA V _{GS} =0V		600	-	-	V
Gate Threshold Voltage	V _{GS(th)}	I _D =250μA V _{DS} =V _{GS}		2.5	3.0	3.5	V
Zero Gate Voltage Drain Current	IDSS	V _{DS} =600V V _{GS} =0V	T _{ch} =25°C	-	-	25	-μA
		V _{DS} =480V V _{GS} =0V	T _{ch} =125°C	-	-	250	
Gate-Source Leakage Current	lass	V _{GS} = ±30V V _{DS} =0V		-	10	100	nA
Drain-Source On-State Resistance	R _{DS(on)}	I _D =15A V _{GS} =10V		-	0.106	0.125	Ω
Gate resistance	RG	f=1MHz, open drain		-	3.2	-	Ω

Dynamic Ratings

Description	Symbol	Conditions	min.	typ.	max.	Unit
Forward Transconductance	g _{fs}	I _D =15A V _{DS} =25V	13	26	-	S
Input Capacitance	Ciss	V _{DS} =10V	-	2200	-	
Output Capacitance	Coss	V _{GS} =0V	-	4670	-	
Reverse Transfer Capacitance	Crss	f=1MHz	-	430	-	
Effective output capacitance, energy related (Note *6)	C _{o(er)}	V _{GS} =0V V _{DS} =0480V	-	127	-	pF
Effective output capacitance, time related (Note *7)	C _{o(tr)}	V _{GS} =0V V _{DS} =0480V ID=constant	-	450	-	-
Turne Ore Time	t _{d(on)}	V _{DD} =400V, V _{GS} =10V I _D =15A, R _G =13Ω See Fig.3 and Fig.4	-	31	-	
Turn-On Time	tr		-	57	-	ns
Trum Off Time	t _{d(off)}		-	136	-	
Turn-Off Time	tr		-	17	-	
Total Gate Charge	QG	V _{DD} =480V, I _D =30A V _{GS} =10V See Fig.5	-	73	-	nC
Gate-Source Charge	Q _{GS}		-	18	-	
Gate-Drain Charge	QGD		-	25	-	
Drain-Source crossover Charge	Qsw		-	11.5	-	1

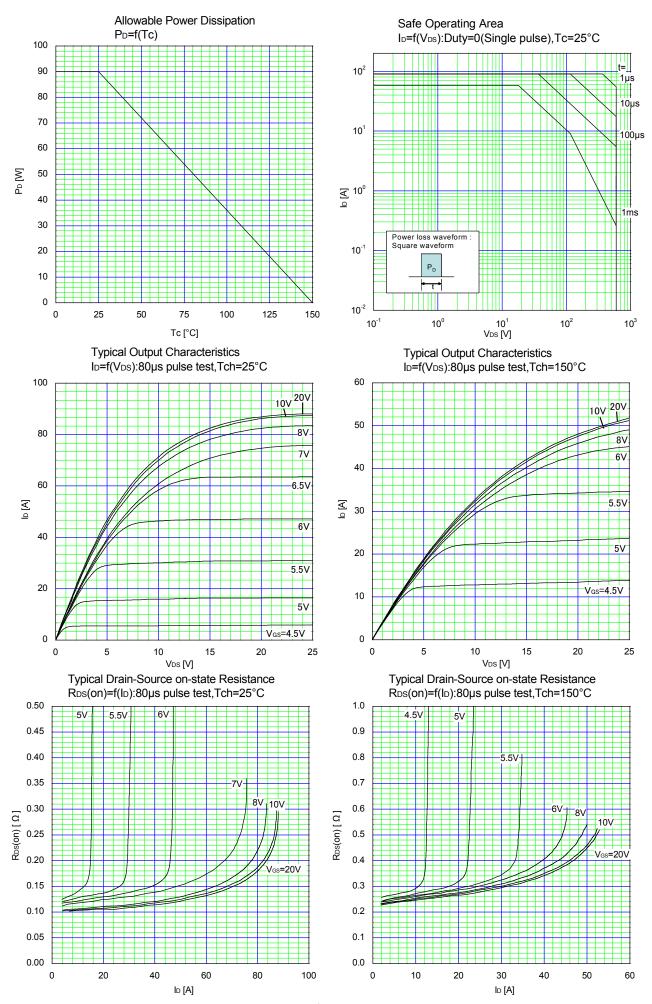
Note *6 : $C_{o(er)}$ is a fixed capacitance that gives the same stored energy as C_{oss} while V_{Ds} is rising from 0 to 80% BV_{DSS}. Note *7 : $C_{o(tr)}$ is a fixed capacitance that gives the same charging times as C_{oss} while V_{Ds} is rising from 0 to 80% BV_{DSS}.

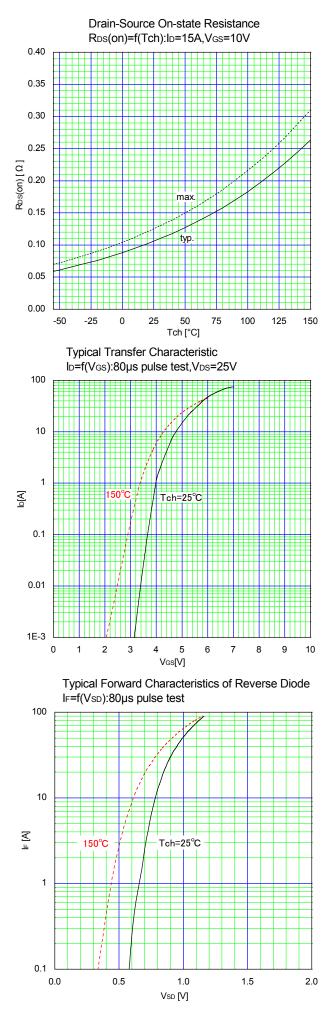
Reverse Diode

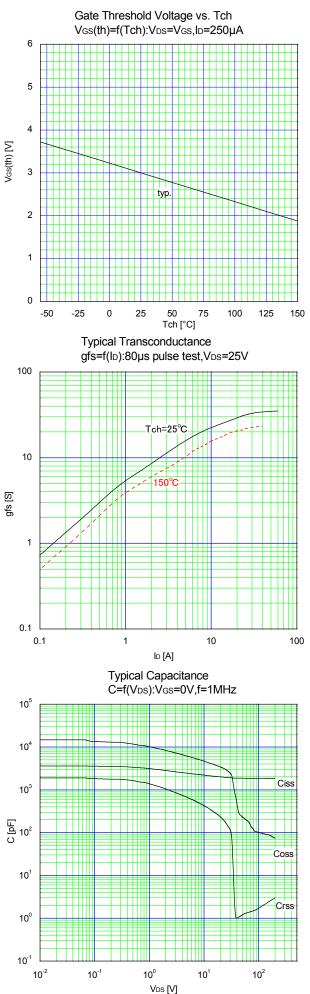
Description	Symbol	Conditions	min.	typ.	max.	Unit
Avalanche Capability	lav	L=21.7mH, T₀ =25°C See Fig.1 and Fig.2	6.6	-	-	А
Diode Forward On-Voltage	V _{SD}	I⊧=30A, V₀s=0V T₀h=25°C	-	0.9	1.35	V
Reverse Recovery Time	trr	I⊧=30A, V₀s=0V	-	430	-	ns
Reverse Recovery Charge	Qrr	V₀₀=400V -di/dt=100A/μs T₅h=25°C See Fig.6	-	8.6	-	μC
Peak Reverse Recovery Current	Irp		-	38	-	А

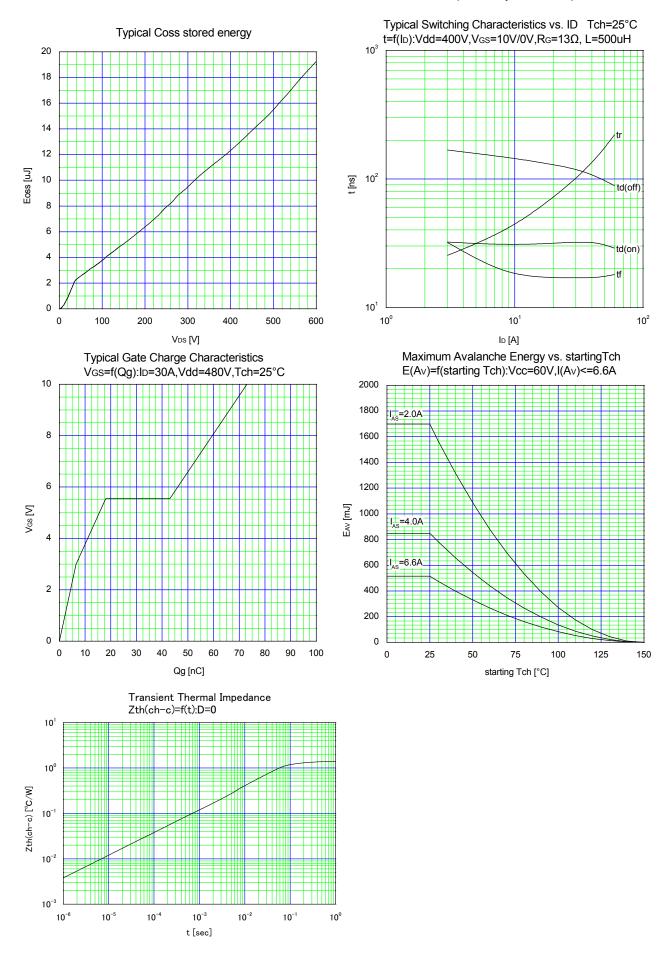
Thermal Characteristics

Description	Symbol	min.	typ.	max.	Unit
Channel to Case	R _{th(ch-c)}	-	-	1.39	°C/W
Channel to Ambient	R _{th(ch-a)}	-	-	58	°C/W









VGS

VDS

DI ID

BVDSS

http://www.fujielectric.com/products/semiconductor/

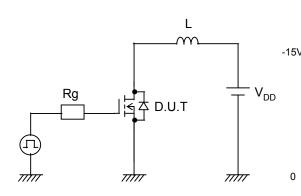
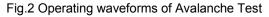


Fig.1 Avalanche Test circuit



IAV

+10V

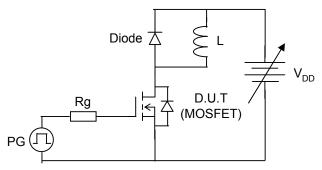


Fig.3 Switching Test circuit

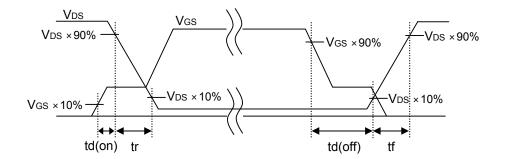


Fig.4 Operating waveform of Switching Test

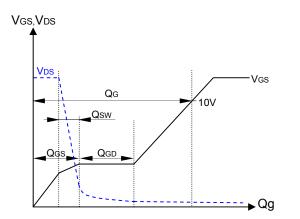
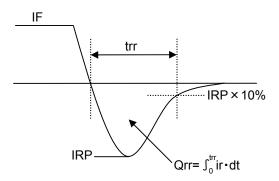
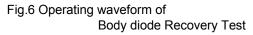
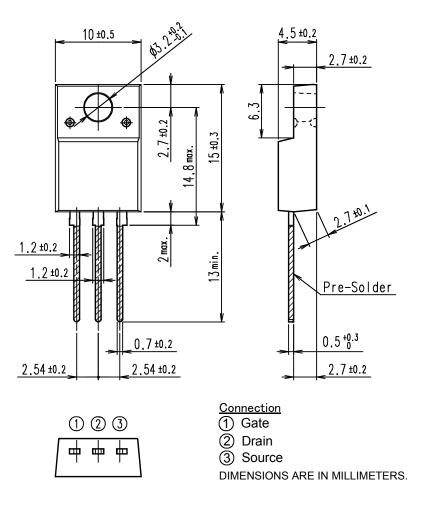


Fig.5 Operating waveform of Gate charge Test

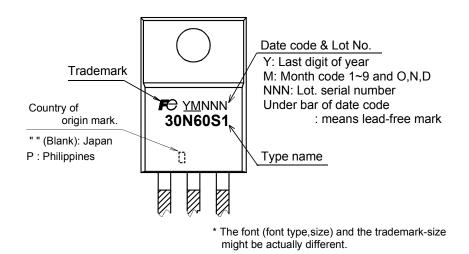




Outview: TO-220F(SLS) Package



Marking



WARNING

- 1. This Catalog contains the product specifications, characteristics, data, materials, and structures as of May 2012. The contents are subject to change without notice for specification changes or other reasons. When using a product listed in this Catalog, be sur to obtain the latest specifications. 2. All applications described in this Catalog exemplify the use of Fuji's products for your reference only. No right or license, either express or implied, under any patent, copyright, trade secret or other intellectual property right owned by Fuji Electric Co., Ltd. is (or shall be deemed) granted. Fuji Electric Co., Ltd. makes no representation or warranty, whether express or implied, relating to the infringement or alleged infringement of other's intellectual property rights which may arise from the use of the applications described herein. 3. Although Fuji Electric Co., Ltd. is enhancing product quality and reliability, a small percentage of semiconductor products may become faulty. When using Fuji Electric semiconductor products in your equipment, you are requested to take adequate safety measures to prevent the equipment from causing a physical injury, fire, or other problem if any of the products become faulty. It is recommended to make your design failsafe, flame retardant, and free of malfunction. 4. The products introduced in this Catalog are intended for use in the following electronic and electrical equipment which has normal reliability requirements. Computers • OA equipment Communications equipment (terminal devices) Measurement equipment Electrical home appliances • Personal equipment • Industrial robots etc. Machine tools Audiovisual equipment 5. If you need to use a product in this Catalog for equipment requiring higher reliability than normal, such as for the equipment listed below, it is imperative to contact Fuji Electric Co., Ltd. to obtain prior approval. When using these products for such equipment, take adequate measures such as a backup system to prevent the equipment from malfunctioning even if a Fuji's product incorporated in the equipment becomes faulty. • Transportation equipment (mounted on cars and ships) Trunk communications equipment Traffic-signal control equipment · Gas leakage detectors with an auto-shut-off feature · Emergency equipment for responding to disasters and anti-burglary devices · Safety devices Medical equipment 6. Do not use products in this Catalog for the equipment requiring strict reliability such as the following and equivalents to strategic equipment (without limitation). Space equipment · Aeronautic equipment Nuclear control equipment Submarine repeater equipment 7. Copyright ©1996-2012 by Fuji Electric Co., Ltd. All rights reserved. No part of this Catalog may be reproduced in any form or by any means without the express permission of Fuji Electric Co., Ltd. 8. If you have any question about any portion in this Catalog, ask Fuji Electric Co., Ltd. or its sales agents before using the product.
 - Neither Fuji Electric Co., Ltd. nor its agents shall be liable for any injury caused by any use of the products not in accordance with instructions set forth herein.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for fuji manufacturer:

Other Similar products are found below :

BZ6WL30CU BZ6WR30CAU BZ6WL30CAU EW100AAG-3P100B EW50AAG-2P015B FMN-60 5V AH165-EG33 AH165-J3C33A AH165-SGLW11E3 AH165-TGL5W11E3 AHX511-L AHX662-A DR30D0L-E3A AR22E0L-10E4G AR22F0L-02H4R AR22G3R-01B AR22G4L-10E3W AR22G4L-11E3A AR22JCR-3A14DC AR22M0R-01B AR22PR-711B AR22S2R-22W AR22VGE-11R AR30E0L-10E3W AR30E0R-11G AR9T511-H EG52F/40-30MA BU-ECA2005L BW9BTAA-L3 BW9BTAA-S2 BW9FWCA-15A BZ6KL10CU 1TR0AK RT11-DC24V SA103RCUL/60 SA103RCUL/75 SA203CUL/125 SA203CUL/200 SA203RCUL/125 SA53RCUL/3 SC-E1-220VAC SC-E5-200V 2NC2F-CK SG103CUL/40-CO SK12LR-E01W AC09-CX0/11L1 EW125JAG-4P030K EW250JAGU-3P200K EW250JAGU-3P225K EW50RAGU-3P003K